

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. . . . . Filed herewith  
Filing Date . . . . . Filed herewith  
Inventor . . . . . Ji Ung Lee et al.  
Assignee . . . . . Micron Technology, Inc.  
Group Art Unit . . . . . Unknown  
Examiner . . . . . Unknown  
Attorney's Docket No. . . . . MI30-068  
Title: "Field Effect Transistor Fabrication Methods, Field Emission Device Fabrication  
Methods, and Field Emission Device Operational Methods"

**PRELIMINARY AMENDMENT**

To: Box Patent Application  
Assistant Commissioner for Patents  
Washington, D.C. 20231

EL844504097

From: James D. Shaurette (Tel. 509-624-4276; Fax 509-838-3424)  
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Sir:

Please enter the following amendments prior to examining the above-identified application:

## AMENDMENTS

### In the Title:

Please replace the title with the following: -FIELD EFFECT TRANSISTOR  
FABRICATION METHODS, FIELD EMISSION DEVICE FABRICATION METHODS,  
AND FIELD EMISSION DEVICE OPERATIONAL METHODS-.